

Electrical Machines and Power Devices and NS Lab (304206)

Teaching Scheme:

Practicals: 4 Hrs/Week

Examination Scheme:

PR: 50 Marks

TW: 50 Marks

Electrical Machines and Power Devices

List of Experiments (Perform any 5 experiments from 1 to 7 and any 2 from the remaining)

1. V-I Characteristics of MOSFET / IGBT
2. V-I Characteristics of thyristor & measurement of holding & latching current.
3. V-I Characteristics of DIAC
4. V-I Characteristics of TRIAC
5. Triggering circuit for MOSFET / IGBT.
6. Triggering circuit for thyristor (Using UJT or IC-785)
7. Light dimmer using TRIAC / Lamp flasher using TRIAC
8. Single phase AC voltage controller using thyristors for R load
7. Load characteristics of D.C. series motor.
8. Brake test on D.C. Shunt motor
9. Load test on 3-phase induction motor.
10. No load & blocked-rotor test on 3-phase induction motor :
 - a. Determination of parameters of equivalent circuit
 - b. Plotting of circle diagram.
11. Report on Industrial visit.

Industrial Visit:-

Minimum One visit to above machines manufacturing industry is recommended.

NS Practical

List of Practicals: (Minimum 4 practicals to be performed using software like MultiSim)

- 1) Consider two port LC network, find all network functions and plot poles and zeros.
- 2) To carry out synthesis of one port LC network into any of the Canonical forms and verify practically.
- 3) To synthesize given transfer function into constant resistance network (Bridge T or Lattice) and verify practically.
- 4) To design 3rd order passive Butterworth/Chebyshev filters and realize/synthesize with scaling of frequency and impedance.
- 5) Design a Butterworth low/high pass filter Sallen Key circuit and verify (at least 2nd order).
- 6) Design a Chebyshev low/high pass filter Sallen Key circuit and verify (at least 2nd order).
- 7) To find gain of biquad op amp circuit & study sensitivity of gain against the different components.
- 8) To study effect of op amp characteristics on filter performance and compensation techniques for the same at least one parameter to be studied practically.